BLF8G20LS-140V; BLF8G20LS-140GV Power LDMOS transistor

AMPLEON

Rev. 3 — 1 September 2015

Product data sheet

Product profile

1.1 General description

140 W LDMOS power transistor for base station applications at frequencies from 1805 MHz to 1990 MHz.

Typical performance Table 1.

Typical RF performance at $T_{case} = 25$ °C in a common source class-AB production test circuit.

Test signal	f	I _{Dq}	V _{DS}	P _{L(AV)}	Gp	η_D	ACPR _{5M}
	(MHz)	(mA)	(V)	(W)	(dB)	(%)	(dBc)
2-carrier W-CDMA	1805 to 1880	900	28	35	18.5	32	-30 <u>[1]</u>

^[1] Test signal: 3GPP test model 1; 64 DPCH; PAR = 8.4 dB at 0.01 % probability on CCDF per carrier; 5 MHz carrier spacing.

1.2 Features and benefits

- Excellent ruggedness
- High efficiency
- Low thermal resistance providing excellent thermal stability
- Decoupling leads to enable improved video bandwidth (150 MHz typical)
- Designed for broadband operation (1805 MHz to 1990 MHz)
- Lower output capacitance for improved performance in Doherty applications
- Designed for low memory effects providing excellent pre-distortability
- Internally matched for ease of use
- Integrated ESD protection
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

RF power amplifiers for base stations and multi carrier applications in the 1805 MHz to 1990 MHz frequency range

2. Pinning information

Table 2. Pinning

	Illing		
Pin	Description	Simplified outline	Graphic symbol
BLF8G20LS-1	140V (SOT1244B)		
1	drain	4 4 5	4
2	gate	4 1 5	6,7→1 1 4,5
3	source [1]		2
4	decoupling lead	3	3
5	decoupling lead		aaa-003619
6	n.c.		
7	n.c.	6 2 7	
BLF8G20LS-1	140GV (SOT1244C)		
1	drain	4 4 5	4
2	gate	4 1 5	6,7 → 4,5
3	source [1]		2
4	decoupling lead		3
5	decoupling lead	6 2 7	aaa-003619
6	n.c.	3	
7	n.c.		

^[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

Type number	Package	Package		
	Name	Description	Version	
BLF8G20LS-140V	-	earless flanged ceramic package; 6 leads	SOT1244B	
BLF8G20LS-140GV	-	earless flanged ceramic package; 6 leads	SOT1244C	

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage		-	65	V
V_{GS}	gate-source voltage		-0.5	+13	V
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature	[1]	-	225	°C

^[1] Continuous use at maximum temperature will affect the reliability, for details refer to the on-line MTF calculator.

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
R _{th(j-c)}	thermal resistance from junction to case	T _{case} = 80 °C; P _L = 35 W	0.4	K/W

6. Characteristics

Table 6. DC characteristics

 $T_i = 25$ °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{(BR)DSS}	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 1.8 \text{ mA}$	65	-	-	V
V _{GS(th)}	gate-source threshold voltage	V _{DS} = 10 V; I _D = 180 mA	1.5	1.8	2.3	V
V_{GSq}	gate-source quiescent voltage	V_{DS} = 28 V; I_{D} = 900 mA	1.6	2	2.4	V
I _{DSS}	drain leakage current	V _{GS} = 0 V; V _{DS} = 28 V	-	-	2.8	μΑ
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	-	33	-	А
I _{GSS}	gate leakage current	V _{GS} = 11 V; V _{DS} = 0 V	-	-	280	nA
g _{fs}	forward transconductance	V _{DS} = 10 V; I _D = 9 A	-	13.35	-	S
R _{DS(on)}	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $I_D = 6.3 \text{ A}$	-	0.08	-	Ω

Table 7. RF characteristics

Test signal: 2-carrier W-CDMA; 3GPP test model 1 with 64 DPCH; PAR = 8.4 dB at 0.01 % probability on the CCDF; f_1 = 1807.5 MHz; f_2 = 1812.5 MHz; f_3 = 1872.5 MHz; f_4 = 1877.5 MHz; RF performance at V_{DS} = 28 V; I_{Dq} = 900 mA; T_{case} = 25 °C; unless otherwise specified; in a water cooled AB test circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
G _p	power gain	P _{L(AV)} = 35 W	17.3	18.5	-	dB
η_{D}	drain efficiency	P _{L(AV)} = 35 W	28	32	-	%
RLin	input return loss	P _{L(AV)} = 35 W	-	-17	-10	dB
ACPR _{5M}	adjacent channel power ratio (5 MHz)	P _{L(AV)} = 35 W	-	-30	-25	dBc

7. Test information

7.1 Ruggedness in class-AB operation

The BLF8G20LS-140V and BLF8G20LS-140GV are capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions: V_{DS} = 28 V; I_{Dq} = 900 mA; P_{L} = 140 W (CW); f = 1800 MHz.

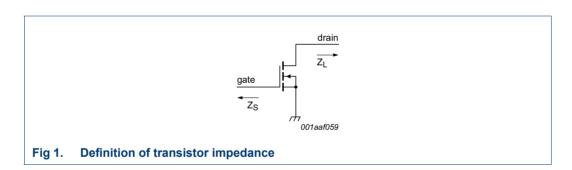
7.2 Impedance information

Table 8. Typical impedance

Measured load-pull data; $I_{Dq} = 900 \text{ mA}$; $V_{DS} = 28 \text{ V}$.

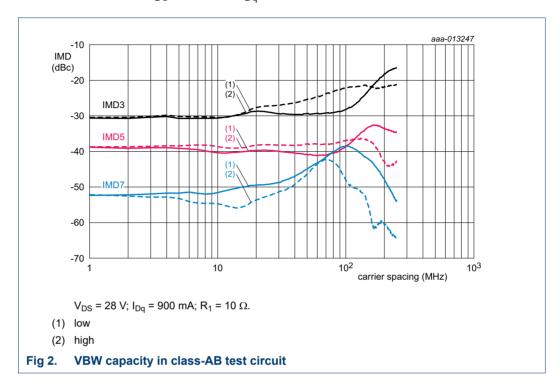
f	Z _S [1]	Z _L [1]
(MHz)	(Ω)	(Ω)
BLF8G20LS-140V		
1805	1.71 – 3.75j	1.5 – 3.7j
1840	2.01 – 4.01j	1.4 – 3.8j
1880	2.35 – 4.08j	1.5 – 3.8j
1930	2.62 – 4.45j	1.6 – 3.9j
1960	3.13 – 4.87j	1.4 – 3.8j
1990	3.93 – 4.54j	1.3 – 3.9j
BLF8G20LS-140GV		
1805	1.71 – 5.75j	1.5 – 5.7j
1840	2.01 – 6.01j	1.4 – 5.8j
1880	2.35 - 6.08j	1.5 – 5.8j
1930	1.62 – 6.45j	1.6 – 5.9j
1960	3.13 – 6.87j	1.4 – 5.8j
1990	3.93 – 6.54j	1.3 – 5.9j

[1] Z_S and Z_L defined in Figure 1.



7.3 VBW in a class-AB operation

The BLF8G20LS-140V and BLF8G20LS-140GV show 150 MHz (typical) video bandwidth (IMD third-order intermodulation inflection point) in a class-AB test circuit in the 1805 MHz to 1880 MHz band at V_{DS} = 28 V and I_{Dg} = 900 mA.



7.4 Test circuit

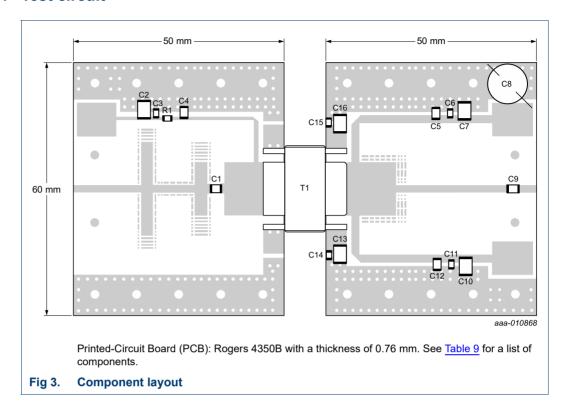


Table 9. List of components

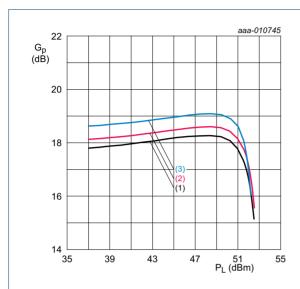
See Figure 3 for component layout.

Component	Description	Value		Remarks
C1	multilayer ceramic chip capacitor	1.2 pF	[1]	ATC 800B
C2	multilayer ceramic chip capacitor	1 μF	[2]	Murata
C3	multilayer ceramic chip capacitor	100 nF	[2]	Murata
C4, C9	multilayer ceramic chip capacitor	12 pF	[1]	ATC 800B
C5, C12	multilayer ceramic chip capacitor	20 pF	[1]	ATC 800B
C6, C11	multilayer ceramic chip capacitor	220 nF	[2]	Murata
C7, C10, C13, C16	multilayer ceramic chip capacitor	4.7 μF, 50 V	[2]	Murata
C8	electrolytic capacitor	> 470 μF, 63 V		
C14, C15	multilayer ceramic chip capacitor	-		not mounted
R1	chip resistor	4.7 Ω, 1 % tolerance		SMD 0805
T1	transistor	-		Ampleon BLF8G20LS-140V

- [1] American Technical Ceramics type 800B or capacitor of same quality.
- [2] Murata or capacitor of same quality.

7.5 Graphical data

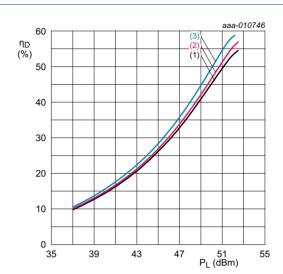
7.5.1 Pulsed CW



 V_{DS} = 28 V; I_{Dq} = 900 mA; t_p = 100 $\mu s; \, \delta$ = 10 %.

- (1) f = 1805 MHz
- (2) f = 1840 MHz
- (3) f = 1880 MHz

Fig 4. Power gain as a function of output power; typical values

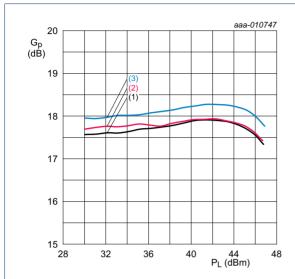


 V_{DS} = 28 V; I_{Dq} = 900 mA; t_p = 100 $\mu s; \, \delta$ = 10 %.

- (1) f = 1805 MHz
- (2) f = 1840 MHz
- (3) f = 1880 MHz

Fig 5. Drain efficiency as a function of out power; typical values

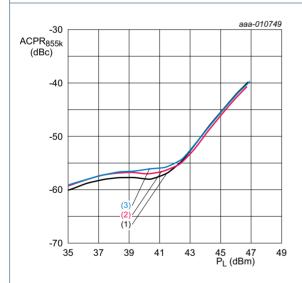
7.5.2 IS-95



 $V_{DS} = 28 \text{ V}; I_{Dq} = 900 \text{ mA}.$

- (1) f = 1810 MHz
- (2) f = 1840 MHz
- (3) f = 1875 MHz

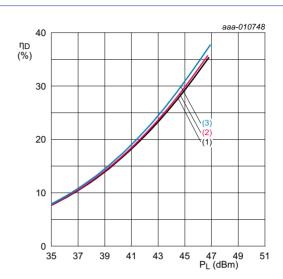
Fig 6. Power gain as a function of output power; typical values



 $V_{DS} = 28 \text{ V}; I_{Dq} = 900 \text{ mA}.$

- (1) f = 1810 MHz
- (2) f = 1840 MHz
- (3) f = 1875 MHz

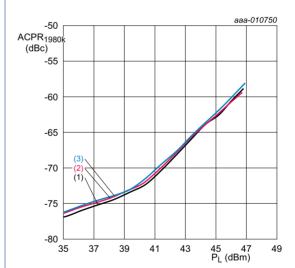
Fig 8. Adjacent channel power ratio (885 kHz) as a function of output power; typical values



 $V_{DS} = 28 \text{ V}; I_{Dq} = 900 \text{ mA}.$

- (1) f = 1810 MHz
- (2) f = 1840 MHz
- (3) f = 1875 MHz

Fig 7. Drain efficiency as a function of output power; typical values



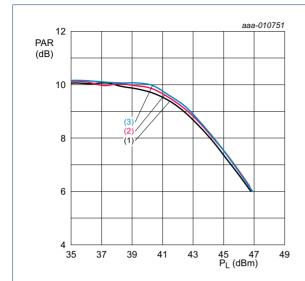
 $V_{DS} = 28 \text{ V}; I_{Dq} = 900 \text{ mA}.$

- (1) f = 1810 MHz
- (2) f = 1840 MHz
- (3) f = 1875 MHz

Fig 9. Adjacent channel power ratio (1980 kHz) as a function of output power; typical values

BLF8G20LS-140(G)V

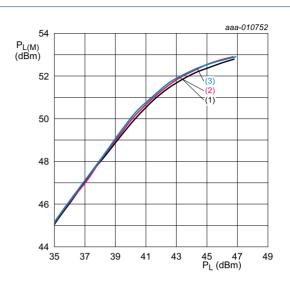
Power LDMOS transistor



 $V_{DS} = 28 \text{ V}; I_{Dq} = 900 \text{ mA}.$

- (1) f = 1810 MHz
- (2) f = 1840 MHz
- (3) f = 1875 MHz

Fig 10. Peak-to-average ratio as a function of output power; typical values

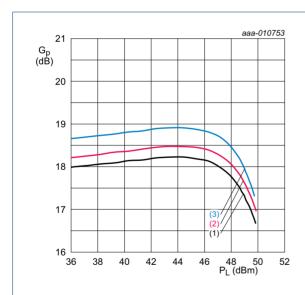


 $V_{DS} = 28 \text{ V}; I_{Dq} = 900 \text{ mA}.$

- (1) f = 1810 MHz
- (2) f = 1840 MHz
- (3) f = 1875 MHz

Fig 11. Peak output power as a function of output power; typical values

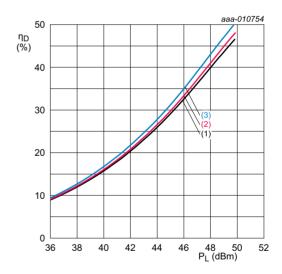
7.5.3 1-Carrier W-CDMA



 V_{DS} = 28 V; I_{Dq} = 900 mA.

- (1) f = 1807.5 MHz
- (2) f = 1840 MHz
- (3) f = 1877.5 MHz

Fig 12. Power gain as a function of output power; typical values



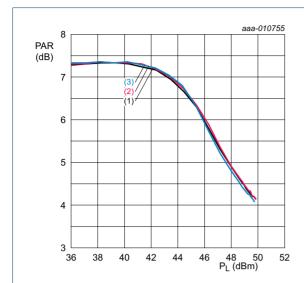
 V_{DS} = 28 V; I_{Dq} = 900 mA.

- (1) f = 1807.5 MHz
- (2) f = 1840 MHz
- (3) f = 1877.5 MHz

Fig 13. Drain efficiency as a function of output power; typical values

BLF8G20LS-140(G)V

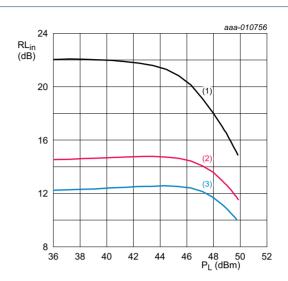
Power LDMOS transistor



 $V_{DS} = 28 \text{ V}; I_{Dq} = 900 \text{ mA}.$

- (1) f = 1807.5 MHz
- (2) f = 1840 MHz
- (3) f = 1877.5 MHz

Fig 14. Peak-to-average ratio as a function of output power; typical values

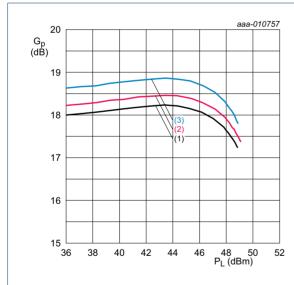


 $V_{DS} = 28 \text{ V}; I_{Dq} = 900 \text{ mA}.$

- (1) f = 1807.5 MHz
- (2) f = 1840 MHz
- (3) f = 1877.5 MHz

Fig 15. Input return loss as a function of output power; typical values

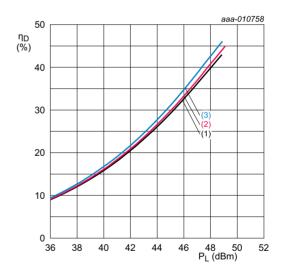
7.5.4 2-Carrier W-CDMA



 $V_{DS} = 28 \text{ V}; I_{Dq} = 900 \text{ mA}.$

- (1) f = 1810 MHz
- (2) f = 1840 MHz
- (3) f = 1875 MHz

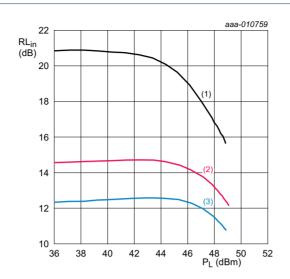
Fig 16. Power gain as a function of output power; typical values



 V_{DS} = 28 V; I_{Dq} = 900 mA.

- (1) f = 1810 MHz
- (2) f = 1840 MHz
- (3) f = 1875 MHz

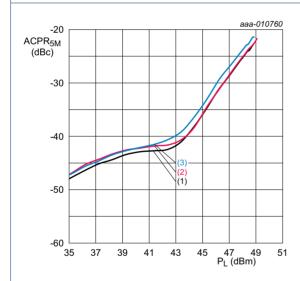
Fig 17. Drain efficiency as a function of output power; typical values



 $V_{DS} = 28 \text{ V}; I_{Dq} = 900 \text{ mA}.$

- (1) f = 1810 MHz
- (2) f = 1840 MHz
- (3) f = 1875 MHz

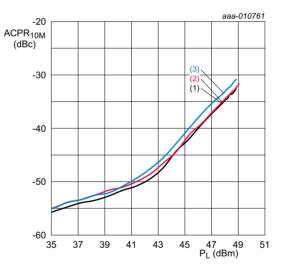
Fig 18. Input return loss as a function of output power; typical values



 $V_{DS} = 28 \text{ V}; I_{Dq} = 900 \text{ mA}.$

- (1) f = 1810 MHz
- (2) f = 1840 MHz
- (3) f = 1875 MHz

Fig 19. Adjacent channel power ratio (5 MHz) as a function of output power; typical values



 $V_{DS} = 28 \text{ V}; I_{Dq} = 900 \text{ mA}.$

- (1) f = 1810 MHz
- (2) f = 1840 MHz
- (3) f = 1875 MHz

Fig 20. Adjacent channel power ratio (10 MHz) as a function of output power; typical values

8. Package outline

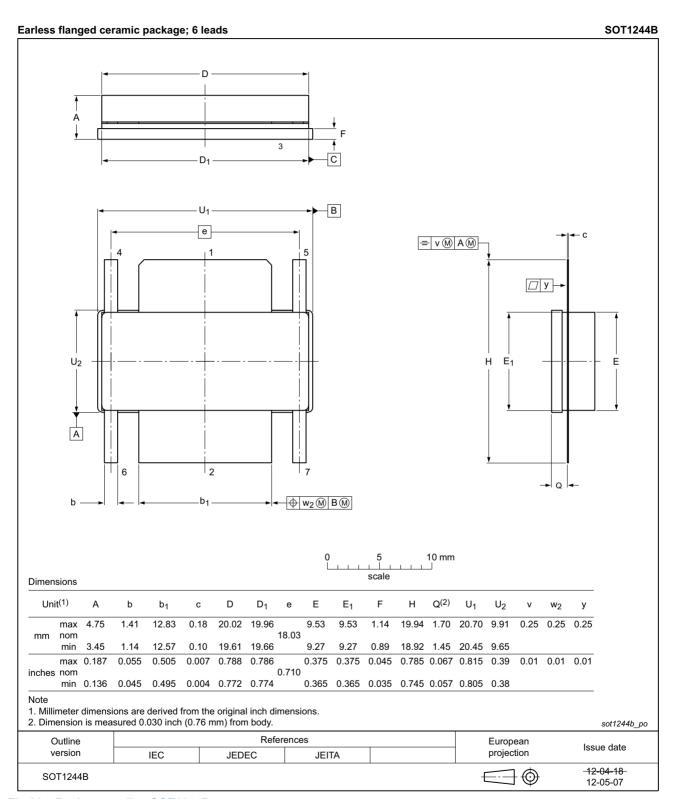


Fig 21. Package outline SOT1244B

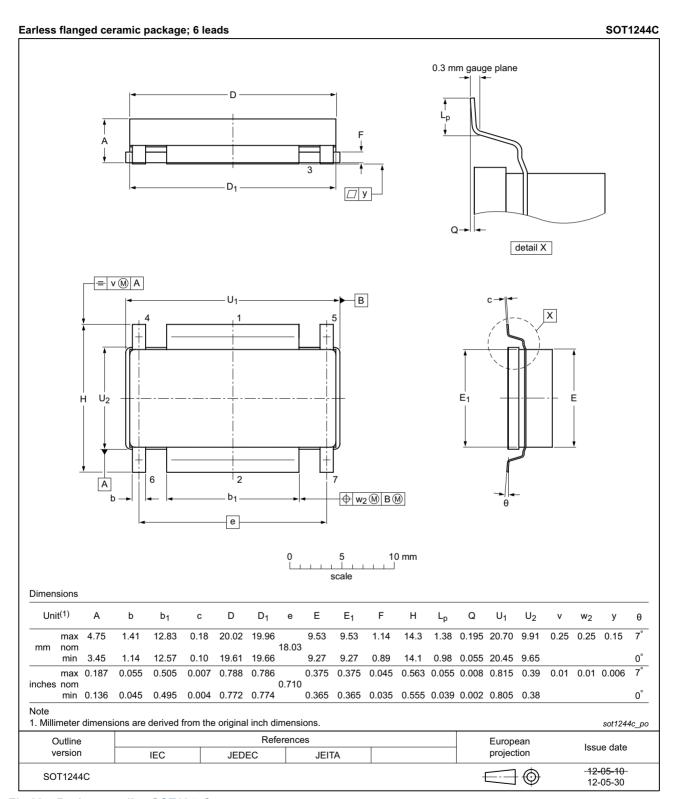


Fig 22. Package outline SOT1244C

9. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the *ANSI/ESD S20.20*, *IEC/ST 61340-5*, *JESD625-A* or equivalent standards.

10. Abbreviations

Table 10. Abbreviations

Acronym	Description
3GPP	3rd Generation Partnership Project
CCDF	Complementary Cumulative Distribution Function
CW	Continuous Wave
DPCH	Dedicated Physical CHannel
ESD	ElectroStatic Discharge
LDMOS	Laterally Diffused Metal Oxide Semiconductor
MTF	Median Time to Failure
PAR	Peak-to-Average Ratio
SMD	Surface Mounted Device
VBW	Video BandWidth
VSWR	Voltage Standing Wave Ratio
W-CDMA	Wideband Code Division Multiple Access

11. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLF8G20LS-140V_20LS-140GV#3	20150901	Product data sheet		BLF8G20LS-140V _20LS-140GV v.2
Modifications:	 The format of this document has been redesigned to comply with the new identity guidelines of Ampleon. Legal texts have been adapted to the new company name where appropriate. 			
BLF8G20LS-140V_20LS-140GV v.2	20141007	Product data sheet	-	BLF8G20LS-140V _20LS-140GV v.1
BLF8G20LS-140V_20LS-140GV v.1	20140207	Objective data sheet	-	-

12. Legal information

12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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BLF8G20LS-140V 20LS-140GV#3

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BLF8G20LS-140(G)V

Power LDMOS transistor

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BLF8G20LS-140(G)V

Power LDMOS transistor

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